MOSFET - Power, Single N-Channel

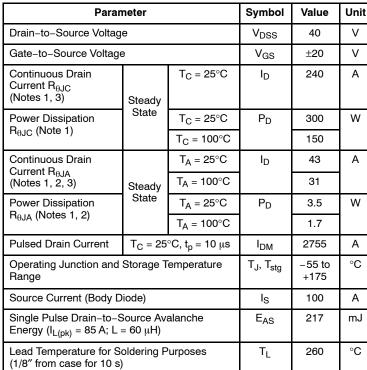
40 V, 1.1 mΩ, 240 A

FDBL9406L-F085

Features

- Small Footprint (TOLL) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T _J = 25° C unless otherwise noted)	



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	0.5	°C/W
Junction-to-Ambient - Steady State (Note 2)	Reia	43	

 The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted. Current is limited by bondwire configuration.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

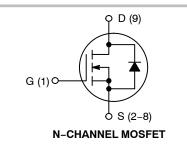
 Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



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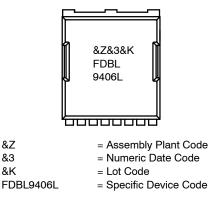
V _{(BR)DSS}	(BR)DSS R _{DS(ON)} MAX	
40 V	1.1 mΩ @ 10 V	80 A
40 V	1.78 mΩ @ 4.5 V	00 A





MO-299A CASE 100CU

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A	40	-	-	V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J		-	19.3	-	mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V_{GS} = 0 V, V_{DS} = 40 V, T_J = 25 $^\circ C$	-	-	1	μΑ
		V_{GS} = 0 V, V_{DS} = 40 V, T_{J} = 175°C	-	-	1	mA
Zero Gate Voltage Drain Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	±100	nA
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage	V _{GS(th)}	$V_{GS}=V_{DS},I_{D}=250\;\mu A$	1	1.9	3	V
Threshold Temperature Coefficient	V _{GS(th)} /T _J		-	-6.5	-	mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I_{D} = 80 A	-	0.9	1.1	mΩ
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 40 \text{ A}$	-	1.25	1.78	
CHARGES, CAPACITANCES & GATE	RESISTANCE		•	•		
Input Capacitance	C _{iss}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 20 V	-	8600	-	pF
Output Capacitance	C _{oss}		-	2380	-	pF
Reverse Transfer Capacitance	C _{rss}		-	106	-	pF
Gate Resistance	Rg	V _{GS} = 0.5 V, f = 1 MHz	-	2	-	Ω
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 32 V, I_{D} = 80 A	-	58	-	nC
		V_{GS} = 10 V, V_{DS} = 32 V, I_{D} = 80 A	-	121	-	
Threshold Gate Charge	Q _{g(th)}	V_{GS} = 0 to 1 V	-	7	-	
Gate-to-Source Gate Charge	Q _{gs}	$V_{DD} = 32 \text{ V}, \text{ I}_{D} = 80 \text{ A}$	-	26	-	
Gate-to-Drain "Miller" Charge	Q _{gd}		-	19	-	
Plateau Voltage	V _{GP}		-	3.2	-	V
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(on)}	$V_{DD} = 20 V, I_D = 80 A,$	-	22	-	ns
Turn-On Rise Time	t _r	V_{GS} = 10 V, R_{GEN} = 6 Ω	-	22	-	ns
Turn-Off Delay Time	t _{d(off)}		-	134	-	ns
Turn-Off Fall Time	t _f		-	44	-	ns
DRAIN-SOURCE DIODE CHARACTEI	RISTICS					
Source-to-Drain Diode Voltage	V _{SD}	$I_{SD} = 80 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	-	0.81	1.25	V
		I_{SD} = 40 A, V_{GS} = 0 V	-	0.77	1.2	V
Reverse Recovery Time	T _{RR}	V_{GS} = 0 V, dI_{SD}/dt = 100 A/µs I_S = 80 A	-	77	-	ns
Charge Time	t _a		-	38	-	
Discharge Time	t _b		-	39	-	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width \leq 300 µs, duty cycle \leq 2%.

95

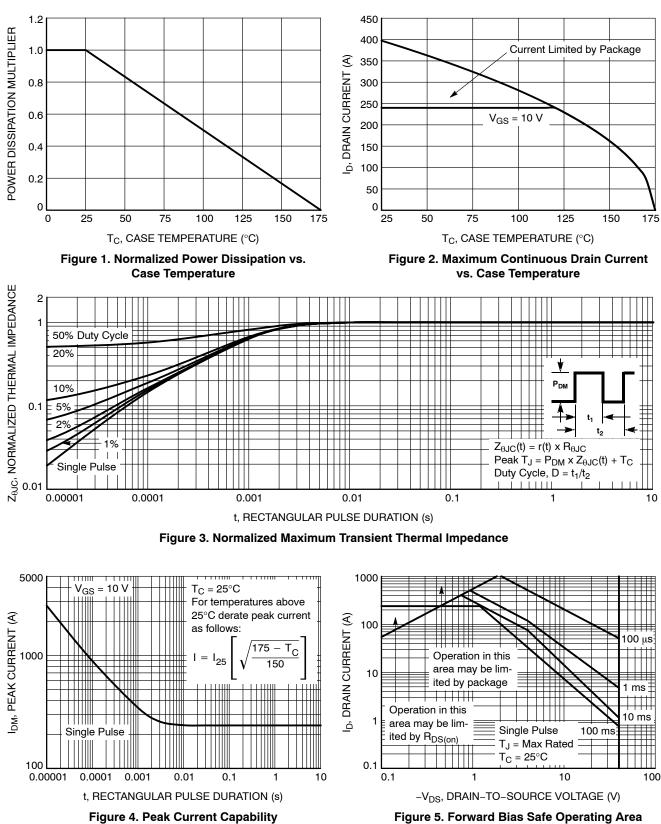
nC

Reverse Recovery Charge

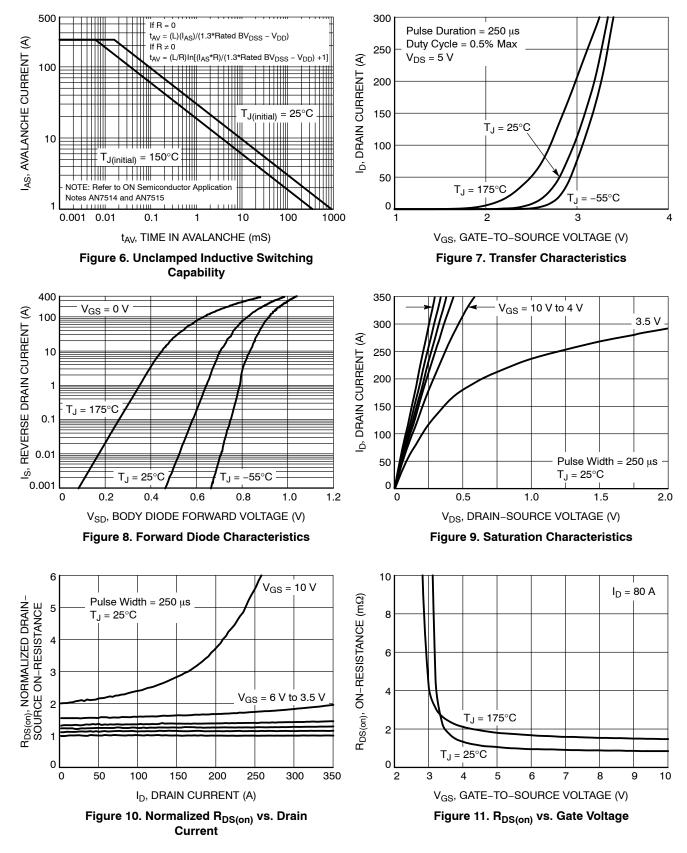
5. Switching characteristics are independent of operating junction temperatures.

Q_{RR}

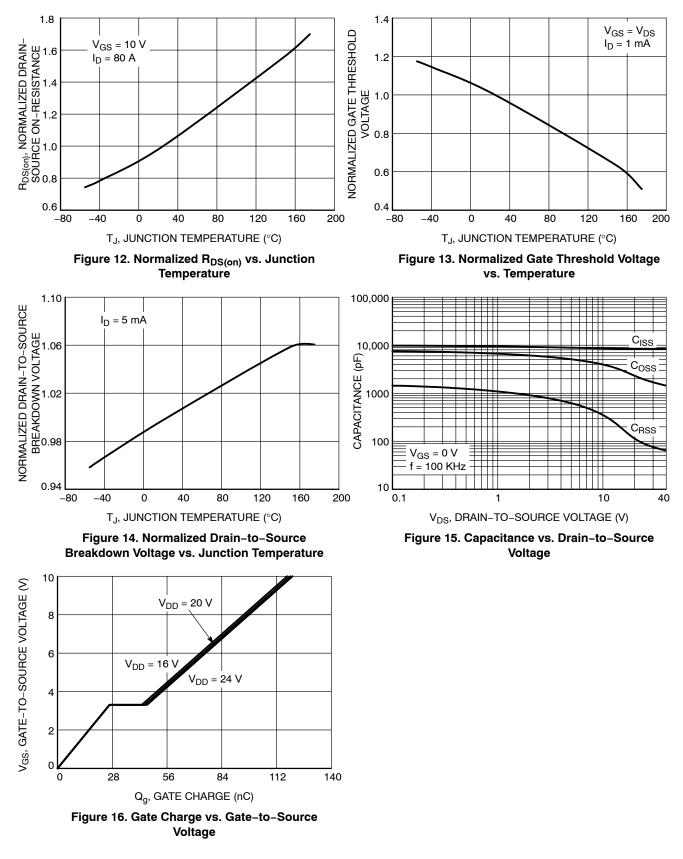
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

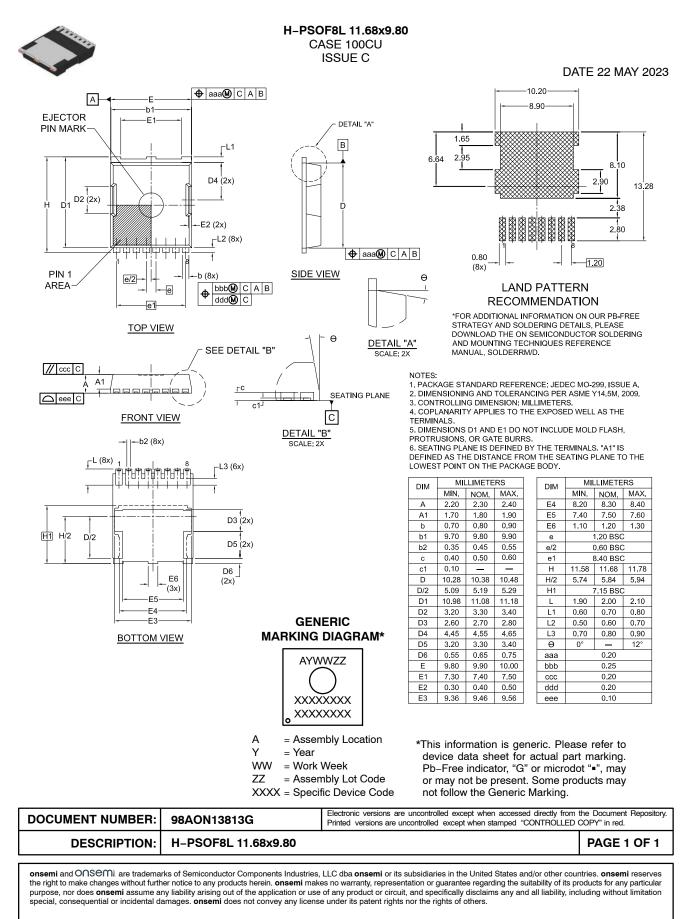


PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Reel Size	Tape Width	Quantity
FDBL9406L-F085	FDBL9406L	H-PSOF8L (Pb-Free / Halogen Free)	13″	24 mm	2000 Units

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

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